



30V P-CHANNEL ENHANCEMENT MODE MOSFET

Totally Lead-Free & Fully RoHS compliant (Note 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability

Case Material: Molded Plastic, "Green" Molding Compound.

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020

Terminal Connections Indicator: See diagram below Terminals: Finish — Matte Tin annealed over Copper lead

frame. Solderable per MIL-STD-202, Method 208 (C3)

Features and Benefits

Low On-Resistance Low Input Capacitance Fast Switching Speed

Mechanical Data

Case: SO-8

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} max | l _D max T _A = +25°C |
|----------------------|----------------------------------|--|
| -30V | 7.5mΩ @ V _{GS} = -10V | -12A |
| -307 | 10.2mΩ @ V _{GS} = -4.5V | -10A |

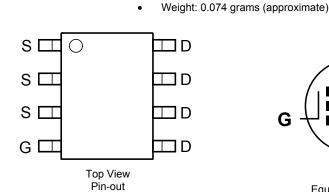
Description

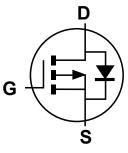
This MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters







Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|------|------------------|
| DMG4413LSS-13 | SO-8 | 2500/Tape & Reel |

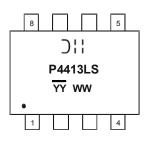
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

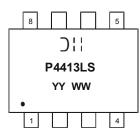
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Chengdu A/T Site



Shanghai A/T Site

)'! = Manufacturer's Marking
P4413LS = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 13 = 2013)
WW = Week (01 - 53)
YY = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Units V | | |
|--|------------------|--|------------------|------------|---|
| Drain-Source Voltage | V _{DSS} | -30 | | | |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 6) V _{GS} = -10V | Steady State | T _A = +25°C T _A = +70°C | I _D | -12 -10 | А |
| | t<10s | T _A = +25°C T _A = +70°C | Ι _D | -22 -17 | А |
| | Steady State | T _A = +25°C T _A = +70°C | ID | -10 -8 | А |
| Continuous Drain Current (Note 6) V_{GS} = -4.5 | t<10s | T _A = +25°C T _A = +70°C | ID | -18 -14 | А |
| Pulsed Drain Current (10µs pulse, duty cycle = 1 | I _{DM} | -100 | А | | |
| Maximum Body Diode continuous Current | | | ls | -4 | А |

Thermal Characteristics

| Characteristic | Symbol | Value | Units | | |
|--|------------------------|----------------------------------|------------|------|--|
| Total Dower Discinction (Note 5) | T _A = +25°C | D | 1.7 | W | |
| Total Power Dissipation (Note 5) | T _A = +70°C | PD | 1.1 | | |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | R _{0JA} | 74 | °C/W | |
| Thermal Resistance, Junction to Ambient (Note 5) | t<10s | RθJA | 22 | | |
| Total Power Dissipation (Note 6) | T _A = +25°C | Р | 2.2 | w | |
| Total Power Dissipation (Note 6) | T _A = +70°C | PD | 1.4 | vv | |
| Thermal Desistance, Junction to Ambient (Note 6) | Steady State | 56 | | | |
| Thermal Resistance, Junction to Ambient (Note 6) | t<10s | R _{0JA} | 17 | °C/W | |
| Thermal Resistance, Junction to Case (Note 6) | Steady State | R _{θJC} | 2.5 | | |
| Operating and Storage Temperature Range | | T _{J.} T _{STG} | -55 to 150 | °C | |

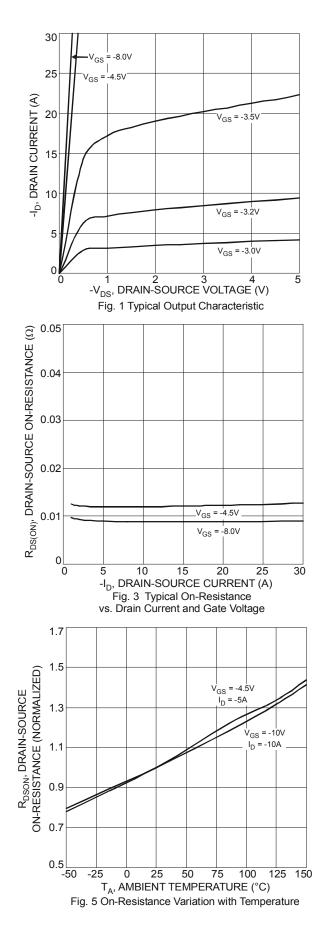
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

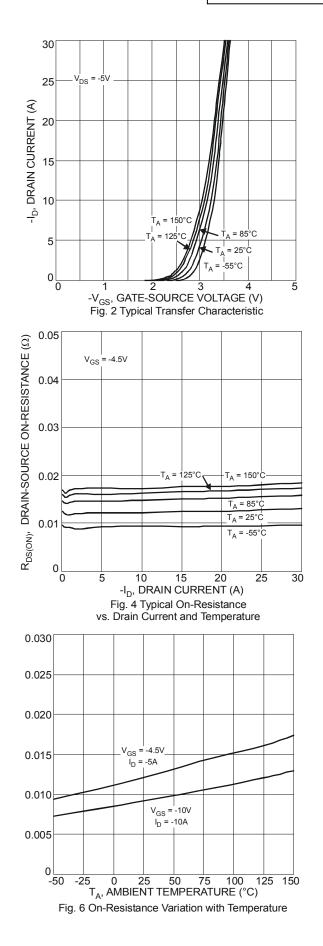
| Characteristic | Symphol | Min | Turn | Max | Unit | Test Condition |
|------------------------------------|---------------------|------|------|------|------|--|
| | Symbol | Min | Тур | wax | Unit | Test Condition |
| OFF CHARACTERISTICS (Note 7) | 51 | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -30 | | | V | V_{GS} = 0V, I_{D} = -250µA |
| Zero Gate Voltage Drain Current | I _{DSS} | | — | -1 | μA | $V_{DS} = -30V, V_{GS} = 0V$ |
| Gate-Source Leakage | I _{GSS} | | | ±1 | μA | V_{GS} = ±20V, V_{DS} = 0V |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | -1.1 | 1.6 | -2.1 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ |
| Static Drain-Source On-Resistance | | _ | 6.3 | 7.5 | 6 | V _{GS} = -10V, I _D = -13A |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 7.9 | 10.2 | mΩ | V_{GS} = -4.5V, I_{D} = -10A |
| Forward Transconductance | g fs | _ | 26 | | S | V _{DS} = -15V, I _D = -13A |
| Diode Forward Voltage | V _{SD} | _ | -0.7 | -1.0 | V | V _{GS} = 0V, I _S = -2.7A |
| DYNAMIC CHARACTERISTICS (Note 8) | • | | | | | · |
| Input Capacitance | Ciss | _ | 4965 | | pF | |
| Output Capacitance | C _{oss} | _ | 1487 | | pF | V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz |
| Reverse Transfer Capacitance | Crss | _ | 711 | — | pF | |
| Gate Resistance | R _G | _ | 7.3 | _ | Ω | V _{DS} = 0V, V _{GS} = 0V f = 1.0MHz |
| SWITCHING CHARACTERISTICS (Note 8) | | | _ | | | |
| Total Gate Charge | Q _G | _ | 46 | | | V _{DS} = -15V, V _{GS} = -5V I _D = -13A |
| Gate-Source Charge | Q _{GS} | _ | 17 | | nC | |
| Gate-Drain Charge | Q _{GD} | _ | 16 | — | | |
| Turn-On Delay Time | t _{d(on)} | _ | 15 | _ | | V _{DS} = -15V, V _{GS} = -10V, |
| Rise Time | tr | _ | 9 | — | ns | |
| Turn-Off Delay Time | t _{d(off)} | _ | 160 | — | 115 | I_{D} = -1A, R_{G} = 6.0 Ω |
| Fall Time | t _f | _ | 66 | | | |

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.

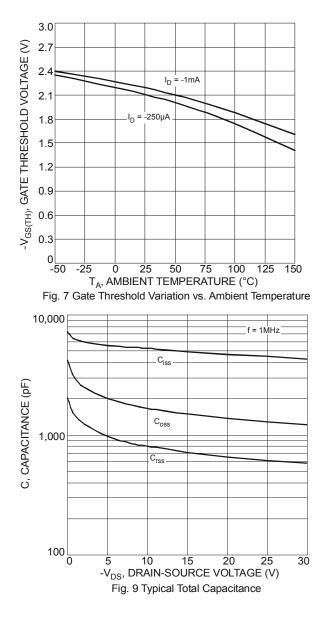
Notes:

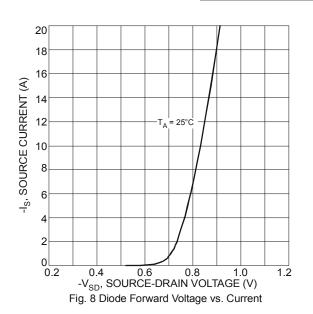






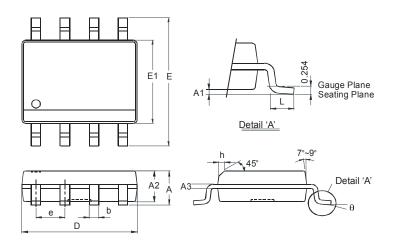






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

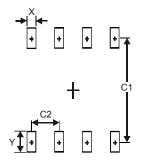


| SO-8 | | | | |
|----------------------|----------|------|--|--|
| Dim | Min | Max | | |
| Α | - | 1.75 | | |
| A1 | 0.10 | 0.20 | | |
| A2 | 1.30 | 1.50 | | |
| A3 | 0.15 | 0.25 | | |
| b | 0.3 | 0.5 | | |
| D | 4.85 | 4.95 | | |
| E | 5.90 | 6.10 | | |
| E1 | 3.85 | 3.95 | | |
| e | 1.27 Typ | | | |
| h | - | 0.35 | | |
| L | 0.62 | 0.82 | | |
| θ | 0° | 8° | | |
| All Dimensions in mm | | | | |



Suggested Pad Layout

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Х | 0.60 |
| Y | 1.55 |
| C1 | 5.4 |
| C2 | 1.27 |

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